

### STI400N4F6, STP400N4F6

# N-channel 40 V, 120 A STripFET™ VI DeepGATE™ Power MOSFET in I<sup>2</sup>PAK and TO-220 packages

Datasheet - preliminary data

#### **Features**

Order codes	V <sub>DSS</sub>	R <sub>DS(on)</sub> max	I <sub>D</sub>
STI400N4F6	40.17	. 1.70	120 A <sup>(1)</sup>
STP400N4F6	40 V	< 1.7 mΩ	120 A**/

- 1. Limited by package
- Low gate charge
- Very low on-resistance
- High avalanche ruggedness

#### **Applications**

■ Switching applications

#### **Description**

These devices are N-channel Power MOSFETs developed using the 6th generation of STripFET<sup>TM</sup> DeepGATE<sup>TM</sup> technology, with a new gate structure. The resulting Power MOSFETs exhibits the lowest  $R_{DS(on)}$  in all packages.

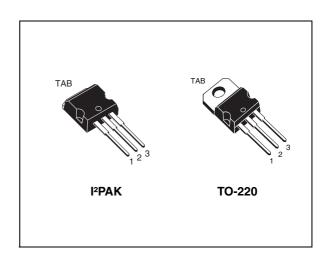


Figure 1. Internal schematic diagram

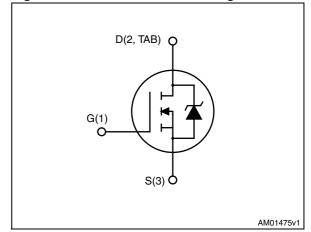


Table 1. Device summary

Order codes	Marking	Package	Packaging
STI400N4F6	400N4F6	I <sup>2</sup> PAK	Tube
STP400N4F6	400114170	TO-220	iube

#### **Contents**

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# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V <sub>DS</sub>	Drain-source voltage	40	V	
V <sub>GS</sub>	Gate-source voltage	± 20	٧	
I <sub>D</sub> <sup>(1)</sup>	Drain current (continuous) at T <sub>C</sub> = 25 °C	120	Α	
I <sub>D</sub> <sup>(1)</sup>	Drain current (continuous) at T <sub>C</sub> = 100 °C	120	Α	
I <sub>DM</sub> <sup>(1)</sup>	Drain current (pulsed)	480	Α	
P <sub>TOT</sub>	Total dissipation at T <sub>C</sub> = 25 °C	300	W	
	Derating factor	2	W/°C	
T <sub>stg</sub>	Storage temperature		°C	
Tj	Operating junction temperature	- 55 to 175		

<sup>1.</sup> Current limited by package

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	0.5	°C/W
R <sub>thj-a</sub>	Thermal resistance junction-ambient max	62.5	°C/W
T <sub>I</sub>	Maximum lead temperature for soldering purpose	300	°C

#### 2 Electrical characteristics

(T<sub>CASE</sub> = 25 °C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)DSS</sub>	Drain-source breakdown voltage (V <sub>GS</sub> = 0)	I <sub>D</sub> = 250 μA	40			V
	Zero gate voltage	V <sub>DS</sub> = 40 V			1	μΑ
I <sub>DSS</sub>	Drain current (V <sub>GS</sub> = 0)	$V_{DS} = 40 \text{ V}, T_{C} = 125 ^{\circ}\text{C}$			100	μΑ
I <sub>GSS</sub>	Gate-body leakage current (V <sub>DS</sub> = 0)	V <sub>GS</sub> = ± 20 V			± 100	nA
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3		4.5	V
R <sub>DS(on)</sub>	Static drain-source on-resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 60 A		TBD	1.7	mΩ

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C <sub>iss</sub>	Input capacitance			20000		pF
C <sub>oss</sub>	Output capacitance	$V_{DS} = 25 \text{ V, f} = 1 \text{ MHz,}$	_	1740	-	pF
$C_{rss}$	Reverse transfer capacitance	V <sub>GS</sub> = 0		1305		pF
$Q_g$	Total gate charge	V 00 V 1 100 A		377		nC
$Q_{gs}$	Gate-source charge	$V_{DD} = 20 \text{ V}, I_D = 120 \text{ A},$ $V_{GS} = 10 \text{ V}$	-	TBD	-	nC
$Q_{gd}$	Gate-drain charge	VGS - 10 V		TBD		nC

Table 6. Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>d(on)</sub>	Turn-on delay time Rise time	$V_{DD} = 20 \text{ V}, I_{D} = 60 \text{ A}$ $R_{G} = 4.7 \Omega V_{GS} = 10 \text{ V}$	-	TBD	-	ns
t <sub>d(off)</sub>	Turn-off-delay time Fall time		-	TBD	-	ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max	Unit
I <sub>SD</sub> <sup>(1)</sup>	Source-drain current		-		120	Α
I <sub>SDM</sub> <sup>(1)</sup>	Source-drain current (pulsed)		-		480	Α
V <sub>SD</sub> <sup>(2)</sup>	Forward on voltage	$I_{SD} = 120 \text{ A}, V_{GS} = 0$	1		1.1	V
t <sub>rr</sub> Q <sub>rr</sub> I <sub>RRM</sub>	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 120 \text{ A}, V_{DD} = 32 \text{ V}$ di/dt = 100 A/ $\mu$ s, $T_j = 150 ^{\circ}\text{C}$	-	TBD		ns nC A

<sup>1.</sup> Current limited by package

<sup>2.</sup> Pulsed: pulse duration = 300  $\mu$ s, duty cycle 1.5%

### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 8. I<sup>2</sup>PAK (TO-262) mechanical data

DIM.		mm.	
Dilvi.	min.	typ	max.
Α	4.40		4.60
A1	2.40		2.72
b	0.61		0.88
b1	1.14		1.70
С	0.49		0.70
c2	1.23		1.32
D	8.95		9.35
е	2.40		2.70
e1	4.95		5.15
E	10		10.40
L	13		14
L1	3.50		3.93
L2	1.27		1.40

 $\begin{array}{c} L2 \\ b1(3x) \\ b (3x) \\ \end{array}$ 

Figure 2. I<sup>2</sup>PAK (TO-262) drawing

Table 9. TO-220 type A mechanical data

D:		mm	
Dim.	Min.	Тур.	Max.
Α	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
Е	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

Figure 3. TO-220 type A drawing

# 4 Revision history

Table 10. Document revision history

Date	Revision	Changes
13-Aug-2012	1	First release.

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